

MJH6284 (NPN), MJH6287 (PNP)

Preferred Device

Darlington Complementary Silicon Power Transistors

These devices are designed for general-purpose amplifier and low-speed switching motor control applications.

Features

- Similar to the Popular NPN 2N6284 and the PNP 2N6287
- Rugged RBSOA Characteristics
- Monolithic Construction with Built-in Collector-Emitter Diode
- Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V_{CEO}	100	Vdc
Collector-Base Voltage	V_{CB}	100	Vdc
Emitter-Base Voltage	V_{EB}	5.0	Vdc
Collector Current - Continuous - Peak	I_C	20 40	Adc
Base Current	I_B	0.5	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	160 1.28	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_{j, \text{st}}$	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.78	$^\circ\text{C/W}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

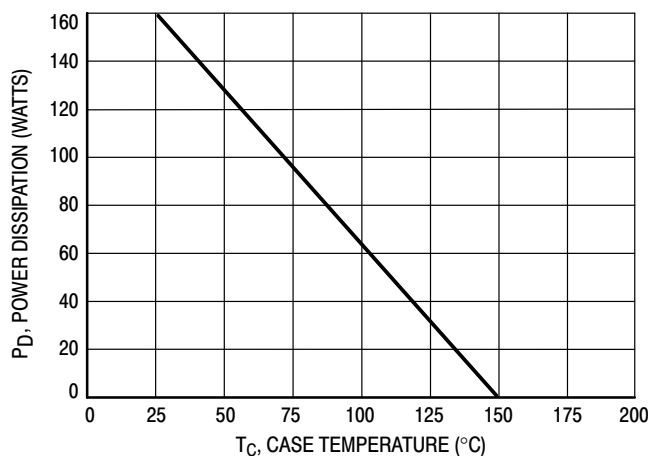


Figure 1. Power Derating

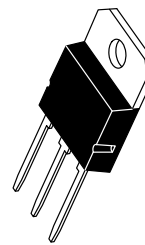
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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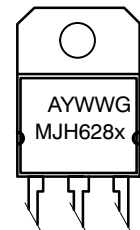
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DARLINGTON 20 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 100 VOLTS, 160 WATTS



SOT-93
(TO-218)
CASE 340D

MARKING DIAGRAM



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A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package
MJH628x = Device Code
x = 4 or 7

ORDERING INFORMATION

Device	Package	Shipping
MJH6284	SOT-93	30 Units / Rail
MJH6284G	SOT-93 (Pb-Free)	30 Units / Rail
MJH6287	SOT-93	30 Units / Rail
MJH6287G	SOT-93 (Pb-Free)	30 Units / Rail

Preferred devices are recommended choices for future use and best overall value.

MJH6284 (NPN), MJH6287 (PNP)

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (I _C = 0.1 Adc, I _B = 0)	V _{CEO(sus)}	100	-	Vdc
Collector Cutoff Current (V _{CE} = 50 Vdc, I _B = 0)	I _{CEO}	-	1.0	mA
Collector Cutoff Current (V _{CE} = Rated V _{CB} , V _{BE(off)} = 1.5 Vdc) (V _{CE} = Rated V _{CB} , V _{BE(off)} = 1.5 Vdc, T _C = 150°C)	I _{CEX}	-	0.5 5.0	mA
Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0)	I _{EBO}	-	2.0	mA
ON CHARACTERISTICS (Note 1)				
DC Current Gain (I _C = 10 Adc, V _{CE} = 3.0 Vdc) (I _C = 20 Adc, V _{CE} = 3.0 Vdc)	h _{FE}	750 100	18,000 -	-
Collector-Emitter Saturation Voltage (I _C = 10 Adc, I _B = 40 mA) (I _C = 20 Adc, I _B = 200 mA)	V _{CE(sat)}	- -	2.0 3.0	Vdc
Base-Emitter On Voltage (I _C = 10 Adc, V _{CE} = 3.0 Vdc)	V _{BE(on)}	-	2.8	Vdc
Base-Emitter Saturation Voltage (I _C = 20 Adc, I _B = 200 mA)	V _{BE(sat)}	-	4.0	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain Bandwidth Product (I _C = 10 Adc, V _{CE} = 3.0 Vdc, f = 1.0 MHz)	f _T	4.0	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	C _{ob}	- -	400 600	pF
				MJH6284 MJH6287
Small-Signal Current Gain (I _C = 10 Adc, V _{CE} = 3.0 Vdc, f = 1.0 kHz)	h _{fe}	300	-	-

SWITCHING CHARACTERISTICS

Characteristic	Symbol	Typical		Unit
		NPN	PNP	
Delay Time	t _d	0.1	0.1	μs
Rise Time	t _r	0.3	0.3	μs
Storage Time	t _s	1.0	1.0	μs
Fall Time	t _f	3.5	2.0	μs

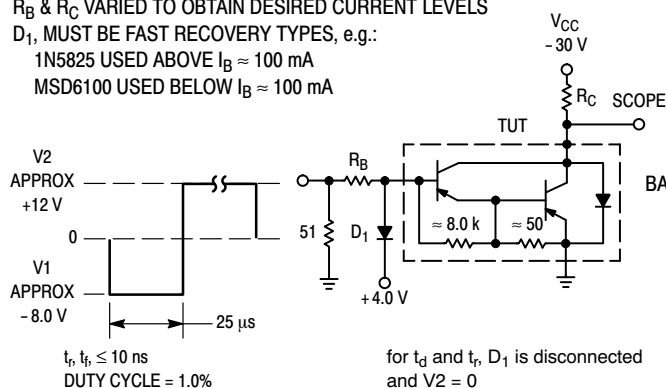
1. Pulse test: Pulse Width = 300 μs, Duty Cycle = 2.0%.

R_B & R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS

D₁, MUST BE FAST RECOVERY TYPES, e.g.:

1N5825 USED ABOVE I_B ≈ 100 mA

M5D6100 USED BELOW I_B ≈ 100 mA



For NPN test circuit reverse diode and voltage polarities.

Figure 2. Switching Times Test Circuit

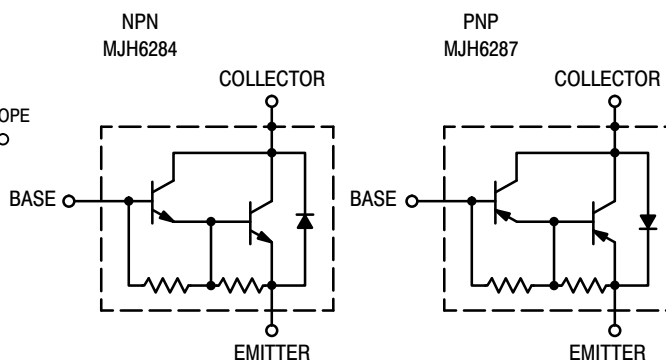


Figure 3. Darlington Schematic

MJH6284 (NPN), MJH6287 (PNP)

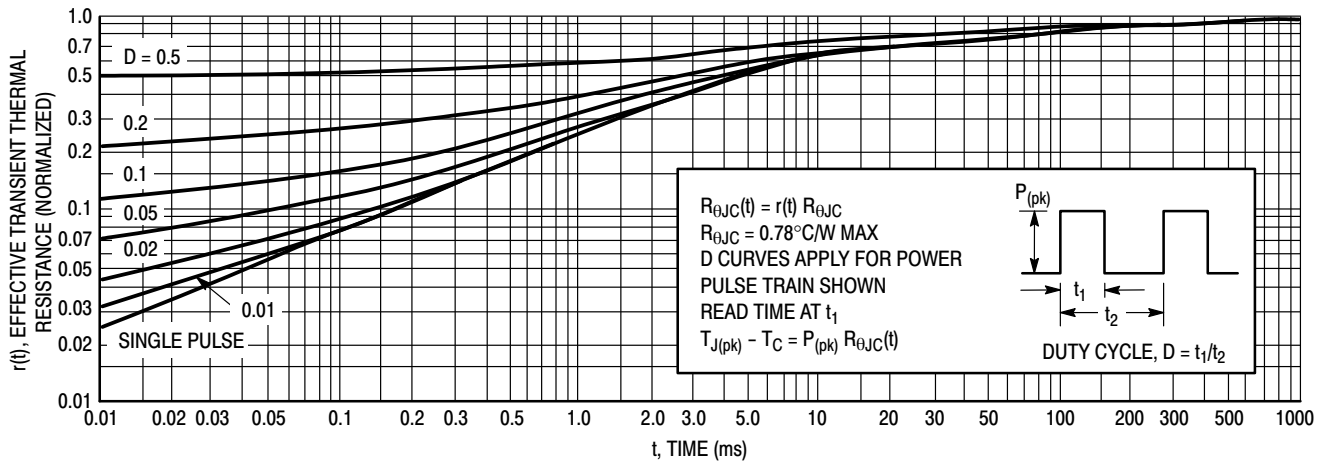


Figure 4. Thermal Response

FBSOA, FORWARD BIAS SAFE OPERATING AREA

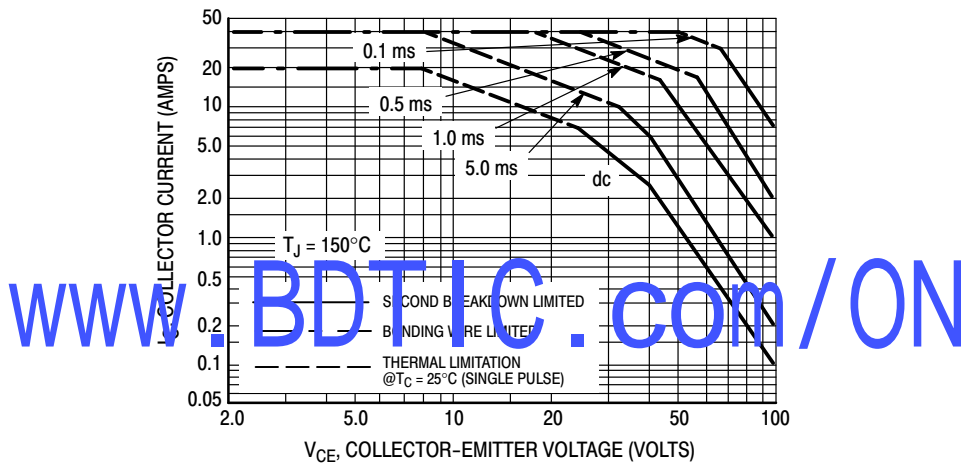


Figure 5. MJH6284, MJH6287

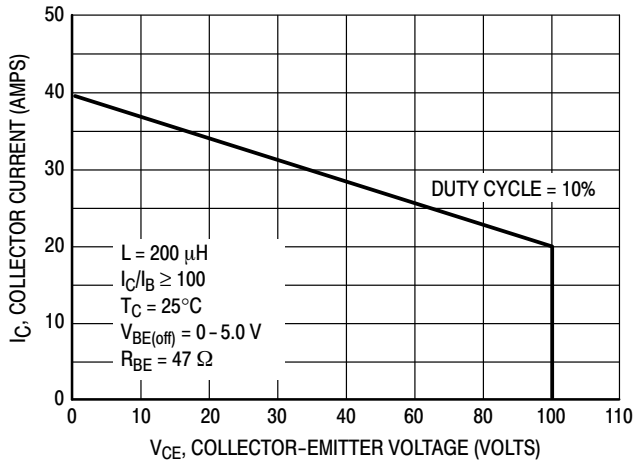


Figure 6. Maximum RBSOA, Reverse Bias Safe Operating Area

FORWARD BIAS

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}\text{C}$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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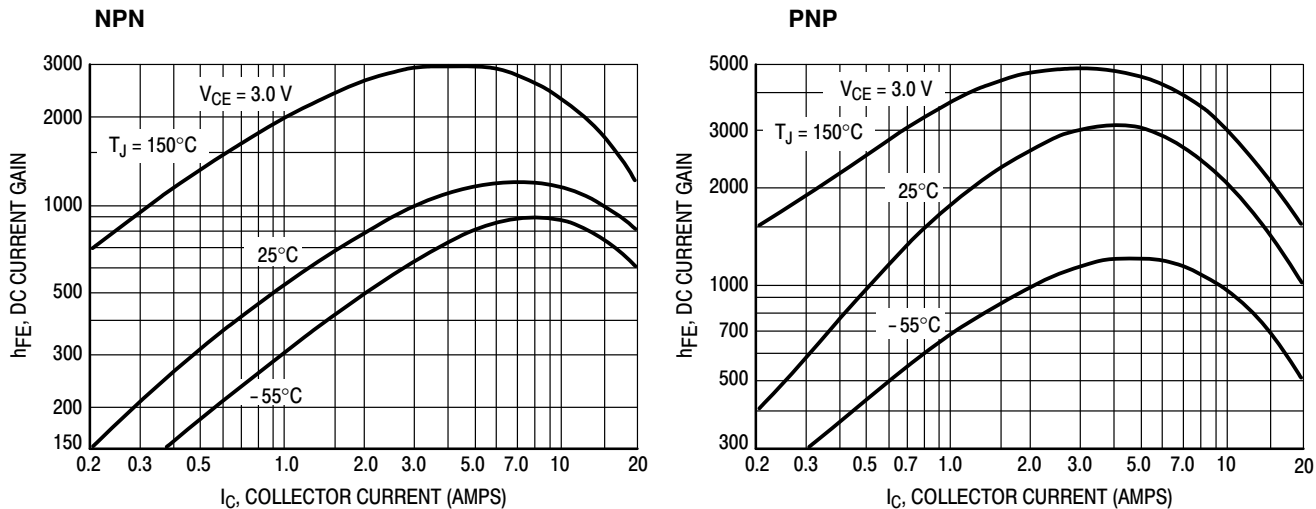


Figure 7. DC Current Gain

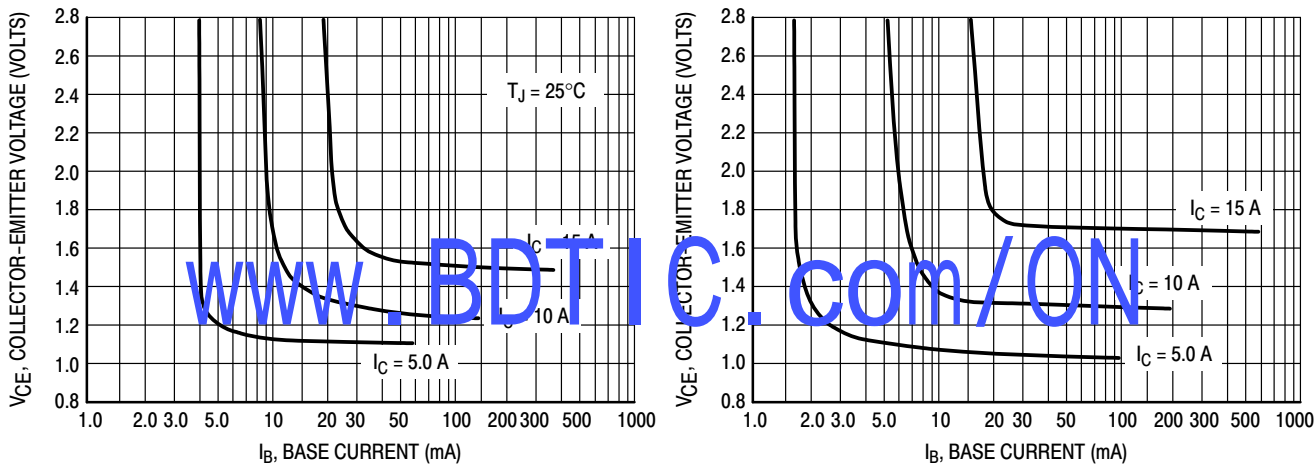


Figure 8. Collector Saturation Region

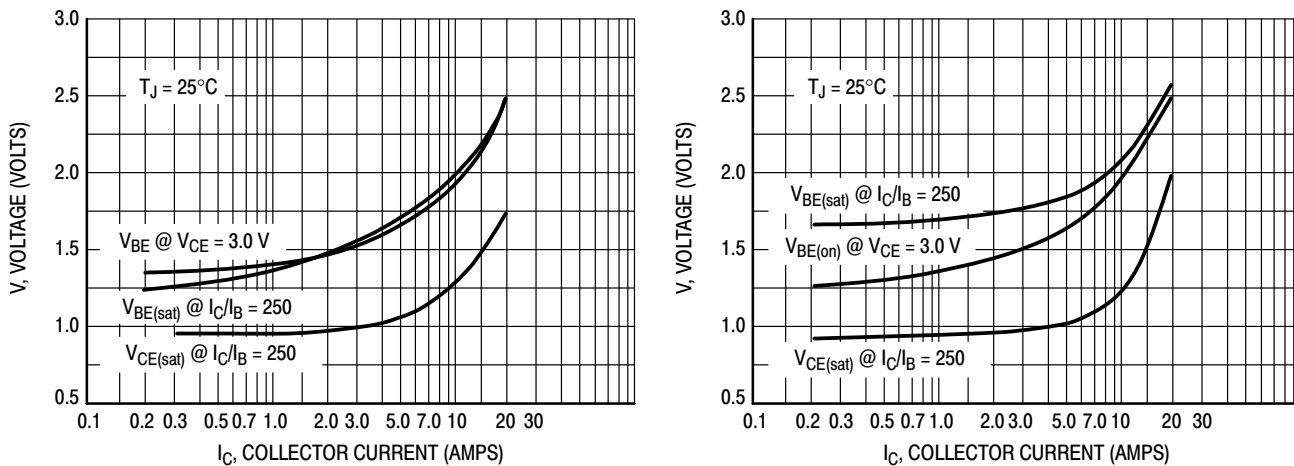
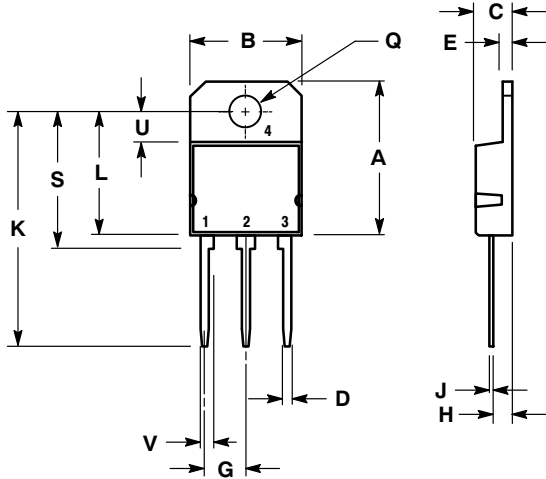


Figure 9. "On" Voltages

MJH6284 (NPN), MJH6287 (PNP)

PACKAGE DIMENSIONS

SOT-93 (TO-218)
CASE 340D-02
ISSUE E



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	20.35	---	0.801
B	14.70	15.20	0.579	0.598
C	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
H	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L	---	16.20	---	0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
V	1.75 REF		0.069	

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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